

**GENERAL DESCRIPTION**

The 840002 is a 2 output LVCMOS/LVTTL Synthesizer optimized to generate Fibre Channel reference clock frequencies. Using a 26.5625MHz, 18pF parallel resonant crystal, the following frequencies can be generated based on the 2 frequency select pins (F\_SEL1:0): 212.5MHz, 159.375MHz, 156.25MHz, 106.25MHz, and 53.125MHz. The 840002 uses low phase noise VCO technology and can achieve 1ps or lower typical rms phase jitter, easily meeting Fibre Channel jitter requirements. The 840002 is packaged in a 16-pin TSSOP package.

**FEATURES**

- Two LVCMOS outputs @ 3.3V, 17Ω typical output impedance
- Selectable crystal oscillator interface or LVCMOS single-ended input
- Output frequency range: 46.66MHz - 233.33MHz
- VCO range: 560MHz - 700MHz
- Supports the following output frequencies: 212.5MHz, 159.375MHz, 156.25MHz, 106.25MHz and 53.125MHz
- RMS phase jitter @ 212.5MHz (637kHz - 10MHz): 0.83ps (typical)

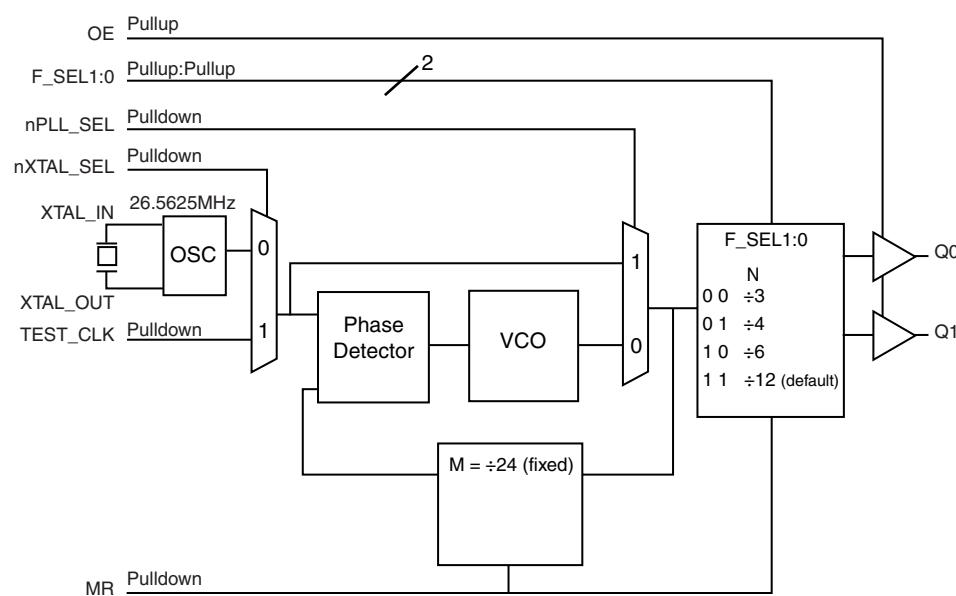
Typical phase noise at 212.5MHz:

Offset	Noise Power
100Hz	-91.3 dBc/Hz
1kHz	-114.3 dBc/Hz
10kHz	-120.7 dBc/Hz
100kHz	-120.2 dBc/Hz

- Full 3.3V or 3.3V core/2.5V output supply modes
- 0°C to 70°C ambient operating temperature
- Available in lead-free RoHS compliant package

**FREQUENCY SELECT FUNCTION TABLE FOR FIBRE CHANNEL APPLICATIONS**

Input Frequency (MHz)	Inputs					Output Frequency (MHz)
	F_SEL1	F_SEL0	M Divider Value	N Divider Value	M/N Ratio Value	
26.5625	0	0	24	3	8	212.5
26.5625	0	1	24	4	6	159.375
26.5625	1	0	24	6	4	106.25
26.5625	1	1	24	12	2	53.125
26.04166	0	1	24	4	6	156.25

**BLOCK DIAGRAM****PIN ASSIGNMENT**

F_SEL0	1	16	F_SEL1
nXTAL_SEL	2	15	GND
TEST_CLK	3	14	GND
OE	4	13	Q0
MR	5	12	Q1
nPLL_SEL	6	11	V <sub>DDO</sub>
V <sub>DDA</sub>	7	10	XTAL_IN
V <sub>DD</sub>	8	9	XTAL_OUT

**840002**  
16-Lead TSSOP  
4.4mm x 5.0mm x 0.92mm  
package body

**G Package**  
Top View

**TABLE 1. PIN DESCRIPTIONS**

Number	Name	Type	Description
1	F_SEL0	Input	Pullup
2	nXTAL_SEL	Input	Pulldown
3	TEST_CLK	Input	Pulldown
4	OE	Input	Pullup
5	MR	Input	Pulldown
6	nPLL_SEL	Input	Pulldown
7	V <sub>DDA</sub>	Power	Analog supply pin.
8	V <sub>DD</sub>	Power	Core supply pin.
9, 10	XTAL_OUT, XTAL_IN	Input	Crystal oscillator interface.
11	V <sub>DDO</sub>	Power	Output supply pin.
12, 13	Q1, Q0	Output	Single-ended clock outputs. LVCMOS/LVTTL interface levels.
14, 15	GND	Power	Power supply ground.
16	F_SEL1	Input	Pullup

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

**TABLE 2. PIN CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
C <sub>PD</sub>	Power Dissipation Capacitance			8		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ
R <sub>OUT</sub>	Output Impedance	3.3V±5%	14	17	21	Ω
		2.5V±5%	16	21	25	Ω

**TABLE 3. FREQUENCY SELECT FUNCTION TABLE**

Input Frequency (MHz)	Inputs					Output Frequency (MHz)
	F_SEL1	F_SEL0	M Divider Value	N Divider Value	M/N Divider Value	
26.5625	0	0	24	3	8	212.5
26.5625	0	1	24	4	6	159.375
26.5625	1	0	24	6	4	106.25
26.5625	1	1	24	12	2	53.125
26.04166	0	1	24	4	6	156.25

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, $V_{DD}$	4.6V
Inputs, $V_I$	-0.5V to $V_{DD} + 0.5$ V
Outputs, $V_O$	-0.5V to $V_{DD} + 0.5$ V
Package Thermal Impedance, $\theta_{JA}$	89°C/W (0 Ifpm)
Storage Temperature, $T_{STG}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

**TABLE 4A. POWER SUPPLY DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 3.3V \pm 5\%$  OR  $2.5V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{DD}$	Core Supply Voltage		3.135	3.3	3.465	V
$V_{DDA}$	Analog Supply Voltage		3.135	3.3	3.465	V
$V_{DDO}$	Output Supply Voltage		3.135	3.3	3.465	V
$I_{DD}$	Power Supply Current				100	mA
$I_{DDA}$	Analog Supply Current				12	mA
$I_{DDO}$	Output Supply Current				5	mA

**TABLE 4B. LVCMOS/LVTTL DC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 3.3V \pm 5\%$  OR  $2.5V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{IH}$	Input High Voltage	F_SEL1:0, nPLL_SEL, nXTAL_SEL, OE, MR		2		$V_{DD} + 0.3$
		TEST_CLK		2		$V_{DD} + 0.3$
$V_{IL}$	Input Low Voltage	F_SEL1:0, nPLL_SEL, nXTAL_SEL, OE, MR		-0.3		0.8
		TEST_CLK		-0.3		1.3
$I_{IH}$	Input High Current	OE, F_SEL0, F_SEL1	$V_{DD} = V_{IN} = 3.465V$		5	$\mu A$
		nPLL_SEL, MR, nXTAL_SEL, TEST_CLK	$V_{DD} = V_{IN} = 3.465V$		150	$\mu A$
$I_{IL}$	Input Low Current	OE, F_SEL0, F_SEL1	$V_{DD} = 3.465V, V_{IN} = 0V$	-150		$\mu A$
		nPLL_SEL, MR, nXTAL_SEL, TEST_CLK	$V_{DD} = 3.465V, V_{IN} = 0V$	-5		$\mu A$
$V_{OH}$	Output High Voltage; NOTE 1		$V_{DDO} = 3.3V \pm 5\%$	2.6		V
			$V_{DDO} = 2.5V \pm 5\%$	1.8		V
$V_{OL}$	Output Low Voltage; NOTE 1		$V_{DDO} = 3.3V$ or $2.5V \pm 5\%$		0.5	V

NOTE 1: Outputs terminated with 50W to  $V_{DDO}/2$ . See Parameter Measurement Information, Output Load Test Circuit.

**TABLE 5. CRYSTAL CHARACTERISTICS**

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation			Fundamental		
Frequency			26.5625		MHz
Equivalent Series Resistance (ESR)				50	$\Omega$
Shunt Capacitance				7	pF
Drive Level				1	mW

NOTE: Characterized using an 18pf parallel resonant crystal.

**TABLE 6A. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = V_{DDO} = 3.3V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{OUT}$	Output Frequency Range	$F\_SEL[1:0] = 00$	186.67		226.67	MHz
		$F\_SEL[1:0] = 01$	140		170	MHz
		$F\_SEL[1:0] = 10$	93.33		113.33	MHz
		$F\_SEL[1:0] = 11$	46.67		56.67	MHz
$tsk(o)$	Output Skew; NOTE 1, 3				12	ps
$jit(\emptyset)$	RMS Phase Jitter (Random); NOTE 2	212.5MHz @ Integration Range: 637kHz - 10MHz		0.83		ps
		159.375MHz @ Integration Range: 637kHz - 10MHz		0.62		ps
		156.25MHz @ Integration Range: 1.875MHz - 20MHz		0.59		ps
		106.25MHz @ Integration Range: 637kHz - 10MHz		0.80		ps
		53.125MHz @ Integration Range: 637kHz - 10MHz		0.68		ps
$t_R / t_F$	Output Rise/Fall Time	20% to 80%	200		700	ps
odc	Output Duty Cycle	$F\_SEL[1:0] = 00$	46		54	%
		$F\_SEL[1:0] = 00$	42		58	%

NOTE 1: Defined as skew between outputs at the same supply voltages and with equal load conditions.

Measured at  $V_{DDO}/2$ .

NOTE 2: Please refer to the Phase Noise Plot.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

**TABLE 6B. AC CHARACTERISTICS,  $V_{DD} = V_{DDA} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ ,  $T_A = 0^\circ C$  TO  $70^\circ C$** 

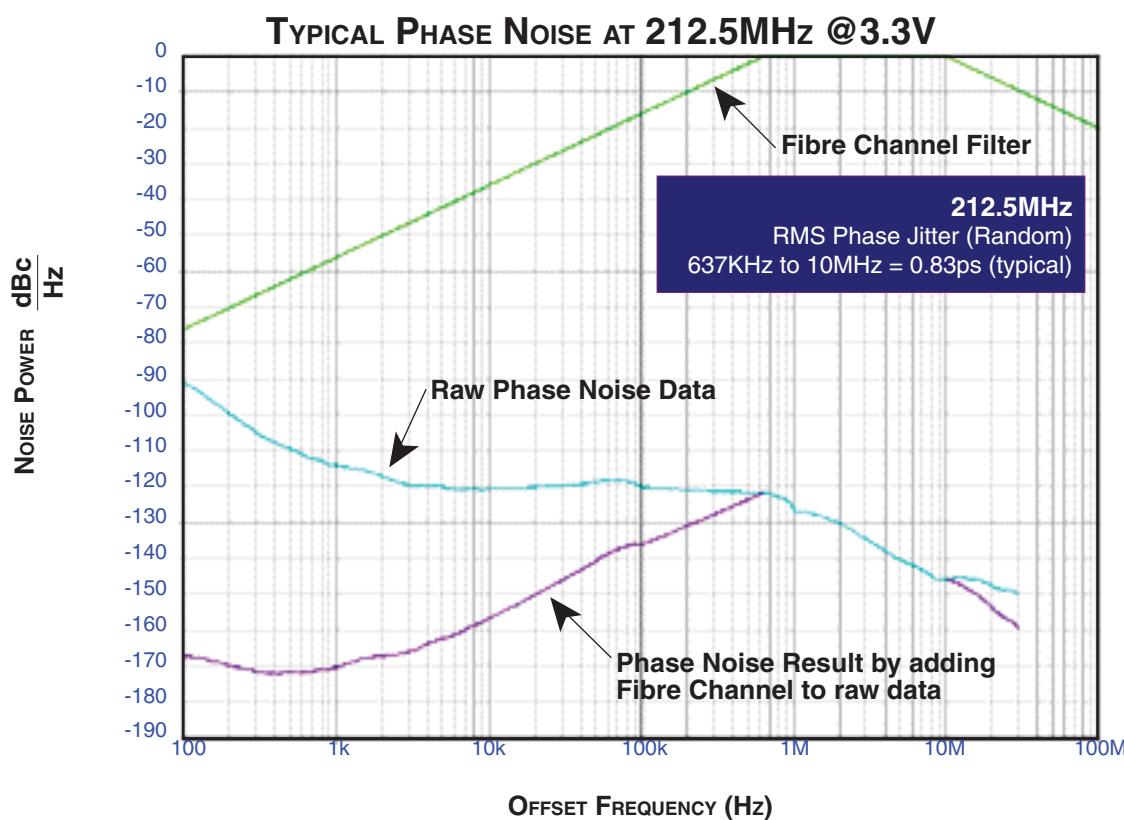
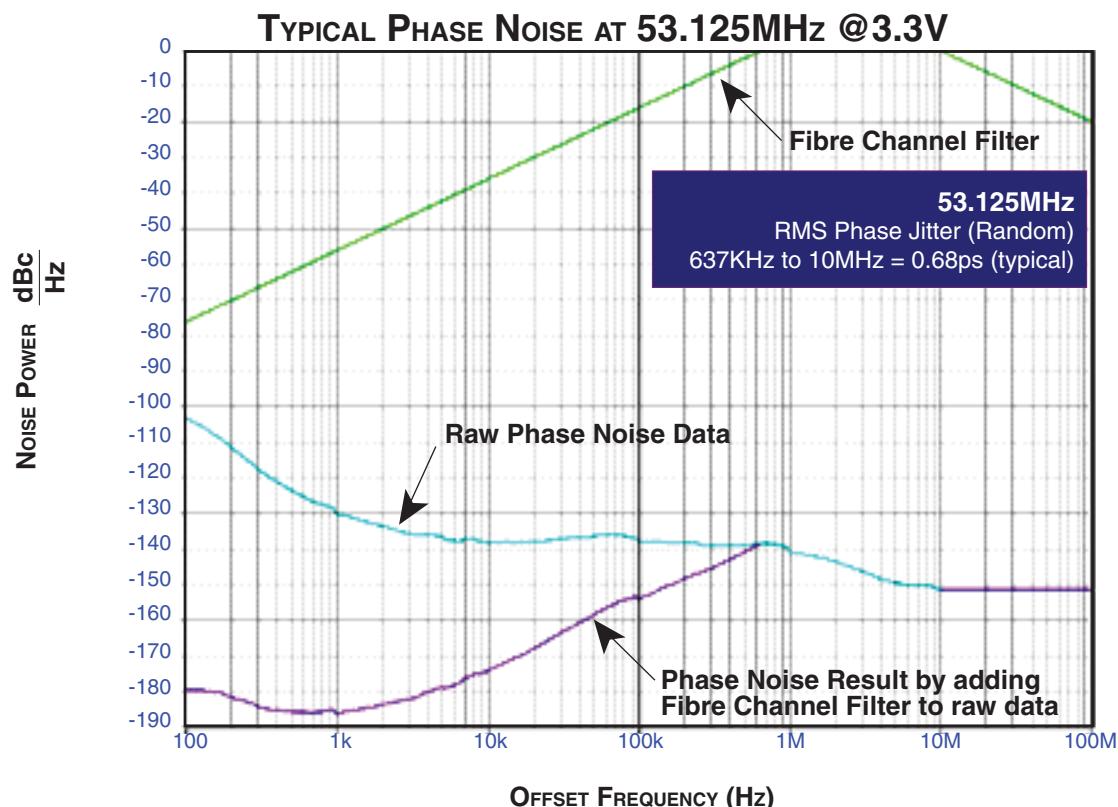
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$f_{OUT}$	Output Frequency Range	$F\_SEL[1:0] = 00$	186.67		226.67	MHz
		$F\_SEL[1:0] = 01$	140		170	MHz
		$F\_SEL[1:0] = 10$	93.33		113.33	MHz
		$F\_SEL[1:0] = 11$	46.67		56.67	MHz
$tsk(o)$	Output Skew; NOTE 1, 3				12	ps
$jit(\emptyset)$	RMS Phase Jitter (Random); NOTE 2	212.5MHz @ Integration Range: 637kHz - 10MHz		0.73		ps
		159.375MHz @ Integration Range: 637kHz - 10MHz		0.62		ps
		156.25MHz @ Integration Range: 1.875MHz - 20MHz		0.56		ps
		106.25MHz @ Integration Range: 637kHz - 10MHz		0.76		ps
		53.125MHz @ Integration Range: 637kHz - 10MHz		0.72		ps
$t_R / t_F$	Output Rise/Fall Time	20% to 80%	200		700	ps
odc	Output Duty Cycle	$F\_SEL[1:0] = 00$	46		54	%
		$F\_SEL[1:0] = 00$	42		58	%

NOTE 1: Defined as skew between outputs at the same supply voltages and with equal load conditions.

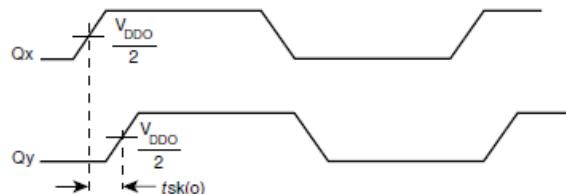
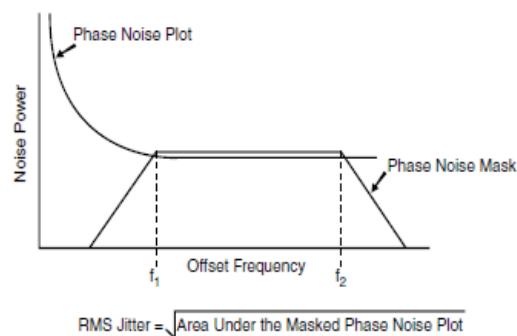
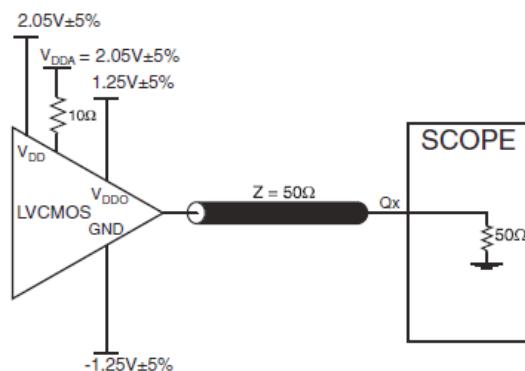
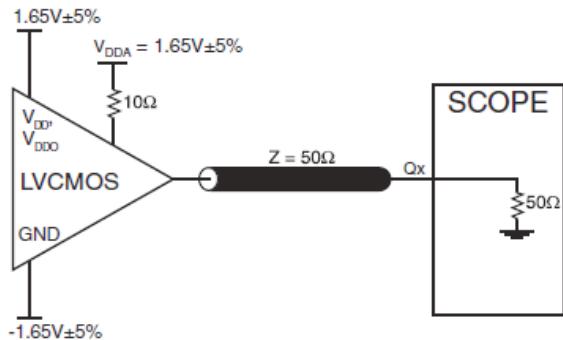
Measured at  $V_{DDO}/2$ .

NOTE 2: Please refer to the Phase Noise Plot.

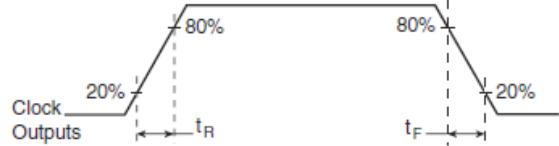
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.



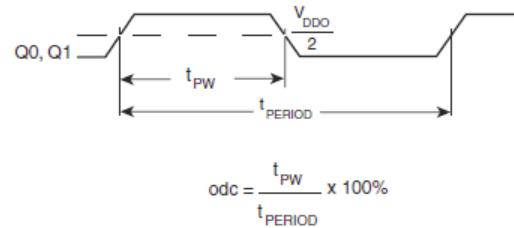
## PARAMETER MEASUREMENT INFORMATION



### RMS PHASE JITTER



### OUTPUT SKEW



### OUTPUT RISE/FALL TIME

## APPLICATION INFORMATION

### POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The 840002 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$ , and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a  $10\Omega$  resistor along with a  $10\mu F$  and a  $.01\mu F$  bypass capacitor should be connected to each  $V_{DDA}$ .

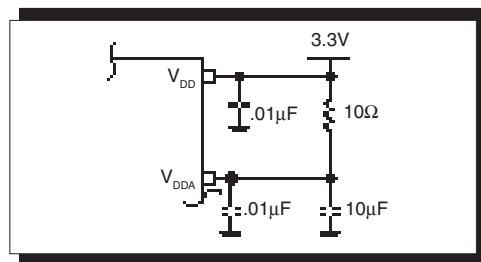


FIGURE 1. POWER SUPPLY FILTERING

### CRYSTAL INPUT INTERFACE

The 840002 has been characterized with 18pF parallel resonant crystals. The capacitor values shown in *Figure 2* below were

determined using a 26.5625MHz, 18pF parallel resonant crystal and were chosen to minimize the ppm error.

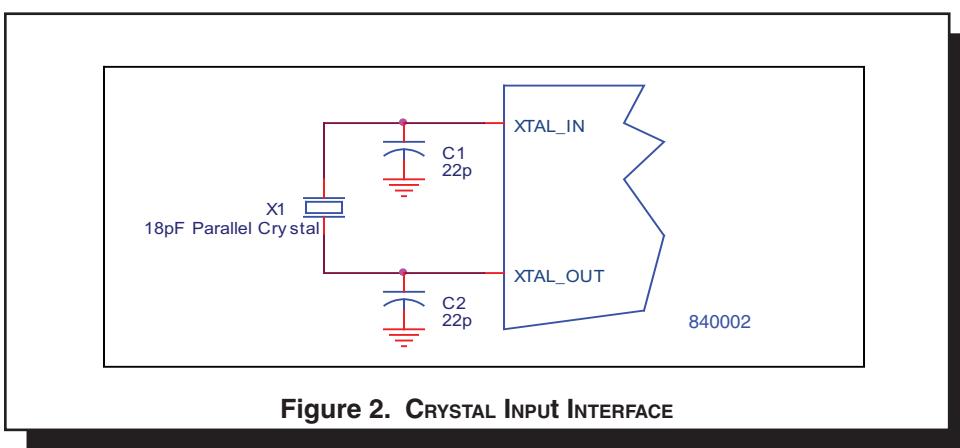


Figure 2. CRYSTAL INPUT INTERFACE

## RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

### INPUTS:

#### CRYSTAL INPUT:

For applications not requiring the use of the crystal oscillator input, both XTAL\_IN and XTAL\_OUT can be left floating. Though not required, but for additional protection, a  $1\text{k}\Omega$  resistor can be tied from XTAL\_IN to ground.

#### TEST\_CLK INPUT:

For applications not requiring the use of the test clock, it can be left floating. Though not required, but for additional protection, a  $1\text{k}\Omega$  resistor can be tied from the TEST\_CLK to ground.

#### LVC MOS CONTROL PINS:

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A  $1\text{k}\Omega$  resistor can be used.

### OUTPUTS:

#### LVC MOS OUTPUT:

All unused LVC MOS output can be left floating. We recommend that there is no trace attached.

## LAYOUT GUIDELINE

Figure 3 shows a schematic example of the 840002. An example of LVC MOS termination is shown in this schematic. Additional LVC MOS termination approaches are shown in the LVC MOS Termination Application Note. In this example, an 18 pF parallel resonant 26.5625MHz crystal is used. The C1=22pF and

C2=22pF are recommended for frequency accuracy. For different board layout, the C1 and C2 may be slightly adjusted for optimizing frequency accuracy.  $1\text{k}\Omega$  pullup or pulldown resistors can be used for the logic control input pins.

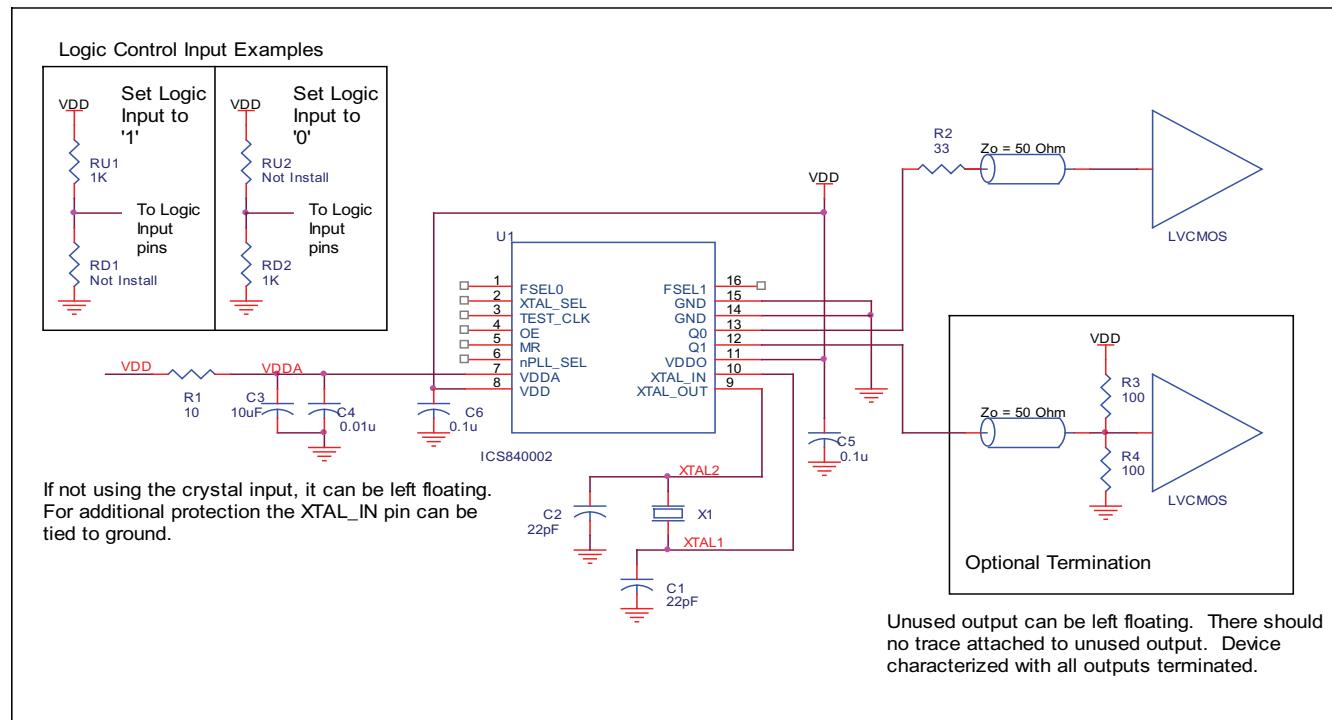


FIGURE 3. 840002 SCHEMATIC EXAMPLE

## RELIABILITY INFORMATION

TABLE 7.  $\theta_{JA}$  vs. AIR FLOW TABLE FOR 16 LEAD TSSOP

### $\theta_{JA}$ by Velocity (Linear Feet per Minute)

	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	137.1°C/W	118.2°C/W	106.8°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	89.0°C/W	81.8°C/W	78.1°C/W

**NOTE:** Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

### TRANSISTOR COUNT

The transistor count for 840002 is: 3085

## PACKAGE OUTLINE - G SUFFIX FOR 16 LEAD TSSOP

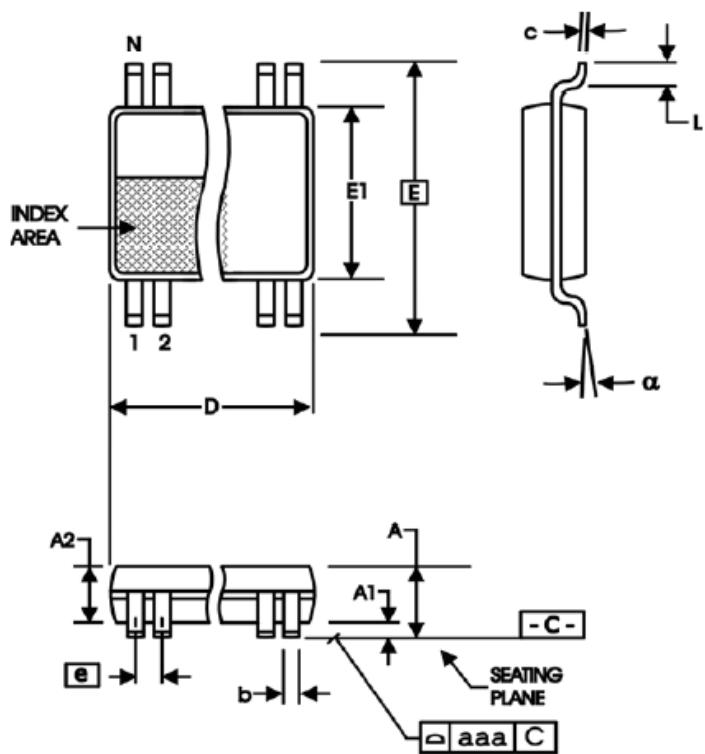


TABLE 8. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	Minimum	Maximum
N	16	
A	--	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 BASIC	
E1	4.30	4.50
e	0.65 BASIC	
L	0.45	0.75
$\alpha$	$0^\circ$	$8^\circ$
aaa	--	0.10

Reference Document: JEDEC Publication 95, MO-153

**TABLE 9. ORDERING INFORMATION**

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
ICS840002AGLF	840002AL	16 Lead "Lead-Free" TSSOP	tube	0°C to 70°C
ICS840002AGLFT	840002AL	16 Lead "Lead-Free" TSSOP	tape & reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

REVISION HISTORY SHEET					
Rev	Table	Page	Description of Change		Date
B	T5 T9	3	Crystal Characteristics Table - added Drive Level.		2/17/06
		6	Updated Output Load AC Test Circuit diagrams.		
		8	Added Recommendations for Unused Input and Output Pins.		
		11	Ordering Information Table - corrected standard marking and added lead-free marking and note.		
C	T9	11	Ordering information - removed leaded devices - PDN CQ-13-02 expired. Updated Datasheet format.		11/10/14



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